PATENT COOPERATION TREATY

PCT

TRANSLATION INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY (Chapter II of the Patent Cooperation Treaty)

(PCT Article 36 and Rule 70)

	nt's or agent's file reference	FOR FURTHER AC	CTION	See Form PCT/IPEA/416			
International application No. International filing		International filing dat	e (day/month/year)	Priority date (day/month/year)			
PCT/EP2005/000500 19.01.			5	18.03.2004			
Internati	onal Patent Classification (IPC) or	national classification and I	PC				
н01	H01L21/331						
Applicant AUSTRIAMICROSYSTEMS AG							
1.	1. This report is the international preliminary examination report, established by this International Preliminary Examining Authority under Article 35 and transmitted to the applicant according to Article 36.						
2.	This REPORT consists of a total of	of	sheets, including this	s cover sheet.			
3.	This report is also accompanied b	y ANNEXES, comprising:					
	a. (sent to the applicant of	and to the International Bur	reau) a total of	sheets, as follows:			
	sheets of the description, claims and/or drawings which have been amended and are the basis for this report and/or sheets containing rectifications authorized by this Authority (see Rule 70.16 and Section 607 of the Administrative Instructions).						
	1 1		•	siders contain an amendment that goes beyond in item 4 of Box No. I and the Supplemental			
		nal Bureau only) a total of (1	indicate type and number	r of electronic carrier(s))			
	o (sem to the fluctuation	in Direction only) a total of (mareate type and number	, containing a sequence listing and/or tables			
		•	d in the Supplemental B	Box Relating to Sequence Listing (see Section			
	802 of the Administrative Instructions).						
4.	This report contains indications re	lating to the following item	s:				
	Box No. I Basis of	the report					
	Box No. II Priority						
	Box No. III Non-est	ablishment of opinion with a	regard to novelty, inventi	ive step and industrial applicability			
	Box No. IV Lack of	unity of invention					
	Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement						
Box No. VI Certain documents cited							
	Box No. VII Certain	defects in the international a	application				
	Box No. VIII Certain	observations on the internat	ional application				
Date of submission of the demand		Date of completion of thi	is report				
Name and mailing address of the IPEA/EP			Authorized officer				
Facsimile No.			Telephone No				

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.
PCT/EP2005/000500

Box	x No. I	Basis of the report		
1.	With	n regard to the language, this report is based on:		
	\boxtimes	the international application in the language in which it wa	as filed	
		the translation of the international application into translation furnished for the purposes of:		, which is the language of a
		international search (Rule 12.3(a) and 23.1(b))		
		publication of the international application (Rule 12.	4(a))	
		international preliminary examination (Rule 55.2(a)	and/or 55.3(a))	
2.	rece	n regard to the elements of the international application, thi iving Office in response to an invitation under Article 14 a report):		
		the international application as originally filed/furnished		
	\boxtimes	the description:		
		pages <u>1-15</u>		as originally filed/furnished
		pages*	received by this Authority on	
		pages*	received by this Authority on	
	\boxtimes	the claims:		
		nos.		as originally filed/furnished
		nos.*	as amended (together wi	th any statement) under Article 19
		nos.* 1-14	18	3.10.2005 with letter
		nos.*		
	\boxtimes	the drawings:		
				as originally filed/furnished
		sheets*		
		sheets*		
	П	a sequence listing and/or any related table(s) – see Suppler		
3.	П		nemai Box Relating to Sequence Listin	±6·
3.	ш	The amendments have resulted in the cancellation of:		
		the description, pages		
		the claims, nos.		
		the sequence listing (specify):		
	$\overline{}$	any table(s) related to sequence listing (specify): This report has been established as if (some of) the amen	dments annexed to this report and list	ed below had not been made since
4.	Ш	they have been considered to go beyond the disclosure as f		
		the description, pages		
		the claims, nos.		
		the drawings, sheets/figs		
		the sequence listing (specify):		
		any table(s) related to sequence listing (specify):		
*	If ite	em 4 applies, some or all of those sheets may be marked "suj	perseded."	

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Box			ticle 35(2) with regard to novelty, inventive step or industrial applicability; oporting such statement	
1.	Statement			
	Novelty (N)	Claims	1-14	YES
		Claims		NO
	Inventive step (IS)	Claims	1-14	YES
		Claims		NO
	Industrial applicability (IA) Claims	1-14	YES
		Claims		NO

- 2. Citations and explanations (Rule 70.7)
 - 1. Reference is made to the following documents:
 - D1: US-A-6 028 345 (JOHNSON ET AL)

 22 February 2000 (2000-02-22) cited in the application
 - D2: EP-A-0 219 243 (MONOLITHIC MEMORIES, INC)
 22 April 1987 (1987-04-22)
 - 2. Document D1 is considered the prior art closest to the subject matter of claim 1 and discloses (the references between parentheses refer to that document): a method for producing a bipolar transistor with a highly doped extrinsic base (110), in which a base layer (108, 110) is provided on a semiconductor substrate (102), in which a doped dielectric layer (118) is deposited, and in which, in a controlled thermal step, the dopant is diffused from the dielectric layer into the semiconductor substrate, resulting in a low-resistance doped extrinsic base (110).
 - 2.2 The subject matter of claim 1 thus differs from that known from D1 in that the dielectric layer is

Box No. V

citations and explanations supporting such statement deposited in a non-doped form and only afterwards is a dopant introduced into the dielectric layer. The dopant (BF $_2$) is introduced following the application of an implantation mask which is structured in such a way that an opening remains in a section provided for the subsequent extrinsic base.

Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability;

- 2.3 The subject matter of claim 1 is thus novel (PCT Article 33(2)).
- 2.4 The aim of the present invention can therefore be considered that of how to avoid the problems associated with the deposition of a highly doped layer.
- 2.5 Document D2 describes (see D2, page 5, line 14 to page 6, line 3) the deposition of an undoped dielectric layer, which is subsequently doped in order to serve as the dopant source for the underlying semiconductor substrate. However, in D2 the layer which is used as the dopant source is an auxiliary layer which is subsequently removed. In addition, the implanted dopant source in D2 is not used to form an extrinsic base and the dopant is not BF2. It is therefore not obvious for a person skilled in the art to arrive at the subject matter of claim 1 from a combination of documents D1 and D2 without thereby being inventive.
- 2.6 Claim 1 thus involves an inventive step (PCT Article 33(3)).

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Box No. V	Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement
2.7	Claims 2-14 are dependent on claim 1 and therefore
	likewise meet the PCT requirements for novelty and
	inventive step.